

MGA-636P8

High Linearity Low Noise Amplifier

AVAGO
TECHNOLOGIES

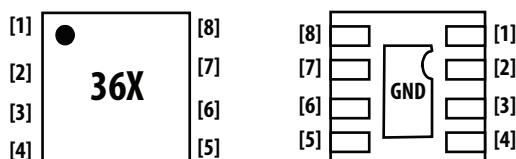
Data Sheet

Description

Avago Technologies' MGA-636P8 is an economical, easy-to-use GaAs MMIC Low Noise Amplifier (LNA). This LNA has low noise and high linearity achieved through the use of Avago Technologies' proprietary 0.25 μm GaAs Enhancement-mode pHEMT process. It is housed in the miniature 2.0 x 2.0 x 0.75 mm³ 8-pin Dual-Flat-Non-Lead (DFN) package. The device is designed for optimum use from 450 MHz up to 1.5 GHz. The compact footprint and low profile coupled with low noise, high gain and high linearity make this an ideal choice as a low noise amplifier for cellular infrastructure applications such as LTE, GSM, CDMA, W-CDMA, CDMA2000 & TD-SCDMA. For optimum performance at lower frequency from 1.5 GHz up to 2.5 GHz, MGA-637P8 is recommended. For optimum performance at higher frequency from 2.5 GHz up to 4 GHz, MGA-638P8 is recommended. All these 3 products, MGA-636P8, MGA-637P8 and MGA-638P8 share the same package and pinout configuration.

Pin Configuration and Package Marking

2.0 x 2.0 x 0.75 mm³ 8-lead DFN



TOP VIEW

BOTTOM VIEW

Pin 1 – Not Used
Pin 2 – RFinput
Pin 3 – Vbias2
Pin 4 – Not Used
Center paddle – GND

Pin 5 – Vbias1
Pin 6 – PwrDwn
Pin 7 – RFoutput
Pin 8 – Not Used

Note:

Package marking provides orientation and identification

"36" = Product Code

"X" = Month Code

It is recommended to ground Pin1, 4 and 8 which are Not Used.

Features

- High linearity performance.
- Low Noise Figure.
- GaAs E-pHEMT Technology^[1].
- Low cost small package size.
- Integrated with active bias and option to access FET gate.
- Integrated power down control pin.

Specifications

700 MHz; 4.8 V, 108 mA

- 18.8 dB Gain
- 0.44 dB Noise Figure
- 11 dB Input Return Loss
- +23.7 dBm Input IP3
- +23.8 dBm Output Power at 1 dB gain compression

Applications

- Cellular infrastructure applications such as LTE, GSM, CDMA, W-CDMA, CDMA2000 & TD-SCDMA.
- Other low noise applications.

Note:

1. Enhancement mode technology employs positive V_{gs}, thereby eliminating the need of negative gate voltage associated with conventional depletion mode devices.



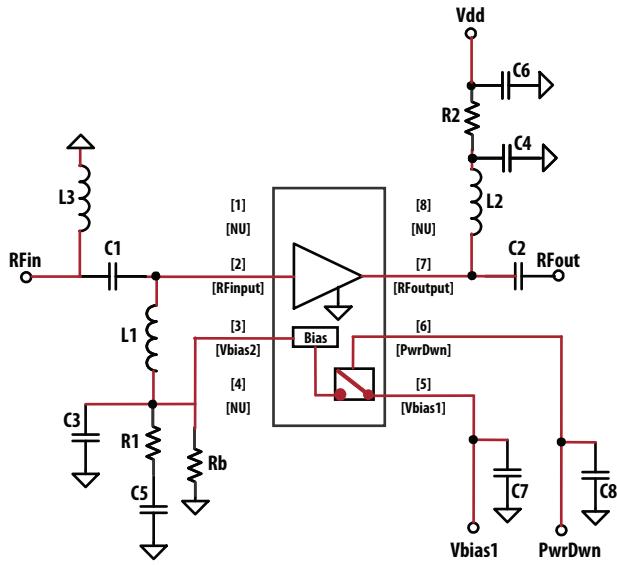
Attention: Observe precautions for handling electrostatic sensitive devices.

ESD Machine Model = 70 V

ESD Human Body Model = 300 V

Refer to Avago Application Note A004R:
Electrostatic Discharge, Damage and Control.

Simplified Schematic^[1]



Note:

1. Device is turned ON when PwrDwn pin is applied with 0 V or left open. Device is turned OFF when PwrDwn pin is applied with 3.3 V.

Absolute Maximum Rating^[1] T_A=25°C

| Symbol | Parameter | Units | Absolute Maximum |
|---------------------|--|-------|------------------|
| V _{dd} | Device Voltage, RF output to ground | V | 5.5 |
| I _{dd} | Drain Current | mA | 130 |
| V _{bias1} | Bias Voltage | V | 5.5 |
| V _{PwrDwn} | Power Down Voltage | V | 5.5 |
| P _{in,max} | CW RF Input Power | dBm | +24 |
| P _{diss} | Total Power Dissipation | W | 0.72 |
| T _j | Junction Temperature | °C | 150 |
| T _{stg} | Storage Temperature | °C | -65 to 150 |

Thermal Resistance

Thermal Resistance^[2]

(V_{dd} = 4.8 V, I_{dd} = 108 mA)

$$\theta_{jc} = 79.6^\circ\text{C/W}$$

Notes:

1. Operation of this device in excess of any of these limits may cause permanent damage.
2. Thermal resistance measured using Infra-Red Measurement Technique.
3. Power dissipation with unit turned on. Board temperature T_c is 25°C. Derate at 12.6 mW/°C for T_c > 93°C.

Electrical Specifications [1, 4]

$T_A = 25^\circ C$, $V_{DD} = V_{bias1} = 4.8 V$, RF measurement at 700 MHz, measured on demo board in Figure 5 with component listed in Table1.

| Symbol | Parameter and Test Condition | Units | Min. | Typ. | Max. |
|---------------------|--|-------|------|------|------|
| I _{DD} | Drain Current | mA | 89 | 108 | 126 |
| I _{PwrDwn} | Current at V _{PwrDwn} pin when V _{PwrDwn} = 3.3 V (Power Down mode) | mA | – | 0.15 | – |
| Gain | Gain | dB | 17.5 | 18.8 | 20.5 |
| NF ^[2] | Noise Figure | dB | – | 0.44 | 0.8 |
| IIP3 ^[3] | Input Third Order Intercept Point | dBm | 22 | 23.7 | – |
| OP1dB | Output Power at 1dB Gain Compression | dBm | – | 23.8 | – |
| IRL | Input Return Loss, 50 Ω source | dB | – | 11 | – |
| ORL | Output Return Loss, 50 Ω load | dB | – | 21 | – |

Notes:

1. Measurements at 700 MHz obtained using demo board described in Figure 5.
2. For NF data, board losses of the input have not been de-embedded.
3. IIP3 test condition: $f_{RF1} = 700$ MHz, $f_{RF2} = 701$ MHz with input power of -10 dBm per tone.
4. Use proper bias, heatsink and derating to ensure maximum channel temperature is not exceeded. See absolute maximum ratings and application note for more details.

Product Consistency Distribution Charts [1, 2]

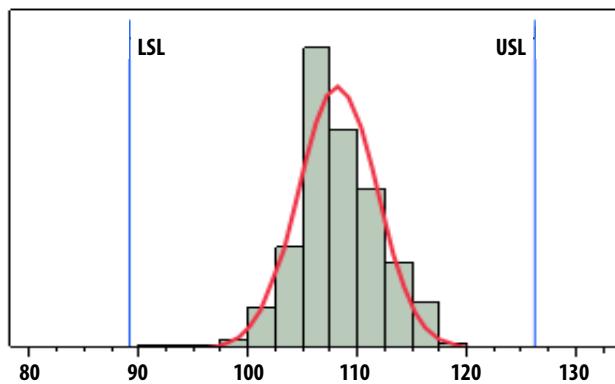


Figure 1. I_{DD}, LSL = 89 mA, nominal = 108 mA, USL = 126 mA

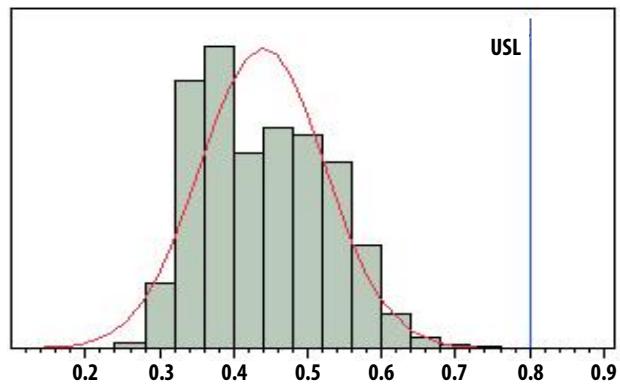


Figure 2. NF, nominal = 0.44 dB, USL = 0.8 dB

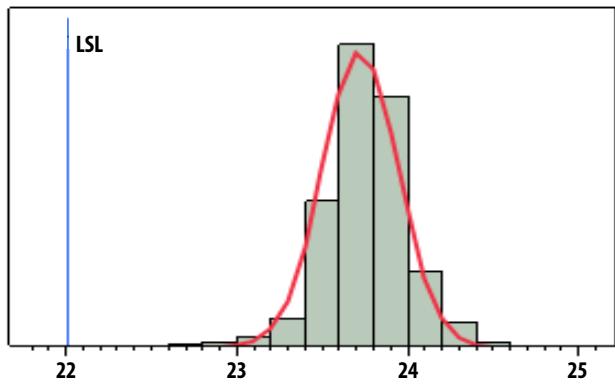


Figure 3. IIP3, LSL = 22 dBm, nominal = 23.7 dBm

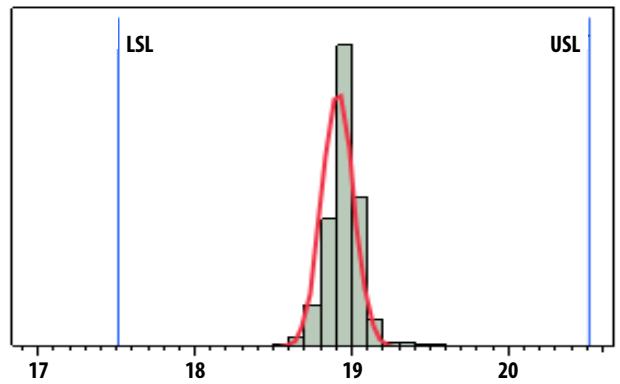


Figure 4. Gain, LSL = 17.5 dB, nominal = 18.8 dB, USL = 20.5 dB

Notes:

1. Distribution data sample size is 500 samples taken from 3 different wafer lots. Future wafers allocated to this product may have nominal values anywhere between the upper and lower limits.
2. Circuit trace losses have not been de-embedded from measurements above.

Demo Board Layout

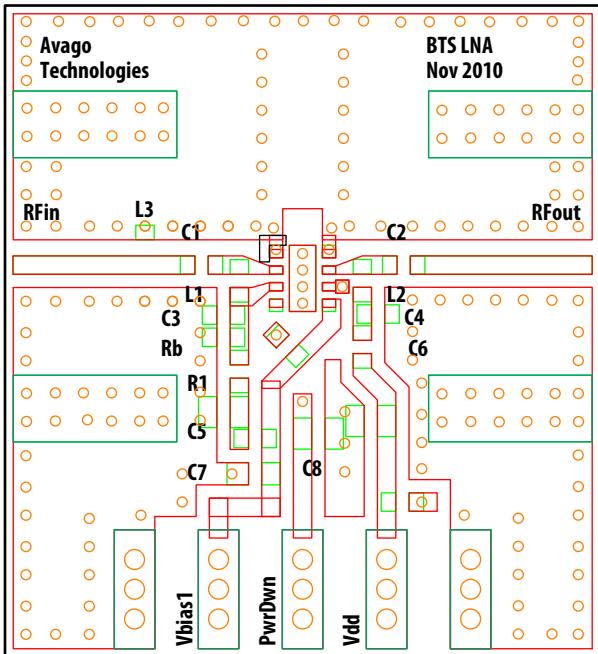
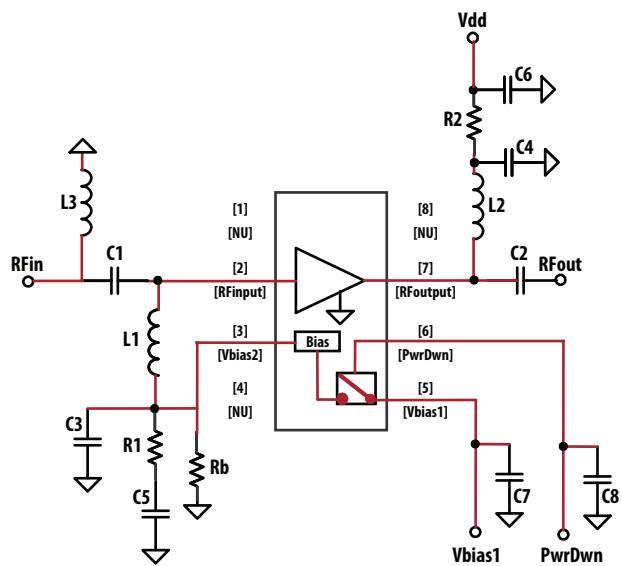


Figure 5. Demo Board Layout Diagram

- Recommended PCB material is 10 mils Rogers RO4350.
- Suggested component values may vary according to layout and PCB material.

Demo Board Schematic



Truth Table

| | $V_{PwrDwn}(V)$ |
|-----------------|-----------------|
| LNA Mode | 0 or open |
| Power Down Mode | 3.3 |

Figure 6. Demo Board Schematic Diagram

Notes:

- The schematic is shown with the assumption that similar PCB is used for all MGA-636P8, MGA-637P8 and MGA-638P8.
- Detail of the components needed for this product is shown in Table 1.

Table 1. Component list for 700 MHz matching

| Part | Size | Value | Detail Part Number |
|----------------|------|----------------------|--------------------|
| C1, C2, C4 | 0402 | 100 pF (Murata) | GRM1555C1H101JD01D |
| C3 | 0402 | 27 pF (Murata) | GRM1555C1H270JA01D |
| C5, C6, C7, C8 | 0402 | 4.7 μ F (Murata) | GRM188R60J475KE19D |
| L1, L2 | 0402 | 33 nH (Toko) | LL1005-FHL33NJ |
| L3 | 0402 | Not Used | |
| Rb | 0402 | Not Used | |
| R1 | 0402 | 51 ohm (Rohm) | MCR004YZPJ510 |
| R2 | 0402 | 0 ohm (Rohm) | MCR01MZPJ000 |

Notes:

C1, C2 are DC blocking capacitors
L1 input match for NF
L2 output match for IP3
C3, C4, C5, C6, C7, C8 are bypass capacitors
R1 is a stabilizing resistor
Rb is the biasing resistor (not used)

Typical Performance

RF performance at $T_A = 25^\circ C$, $V_{dd} = 4.8 V$, $I_{dd} = 100 mA$, measured using 50 ohm input and output board unless stated otherwise. IIP3 test condition: $F_{RF1}-F_{RF2} = 1 MHz$ with input power of -10 dBm per tone.

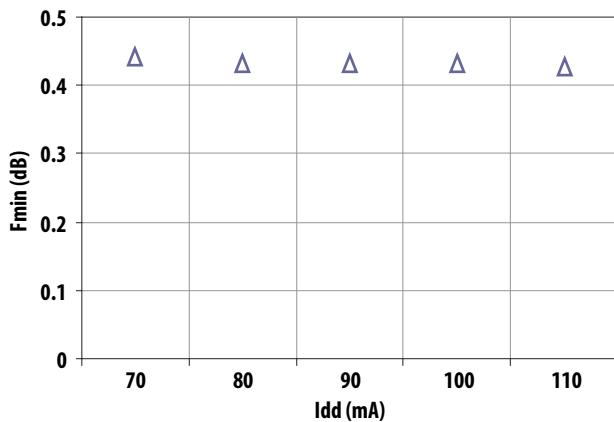


Figure 7. F_{min} vs I_{dd} at 4.8 V at 700 MHz

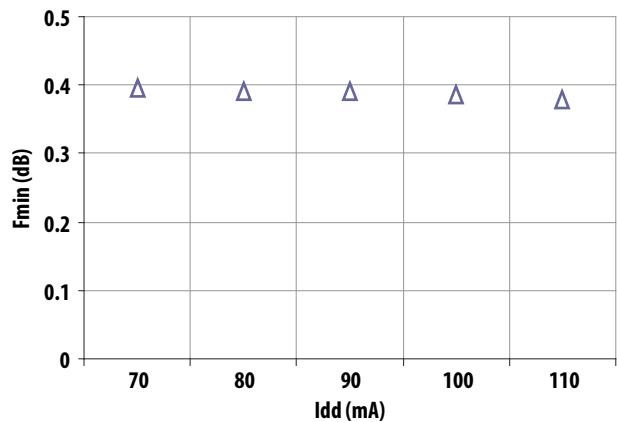


Figure 8. F_{min} vs I_{dd} at 4.8 V at 900 MHz

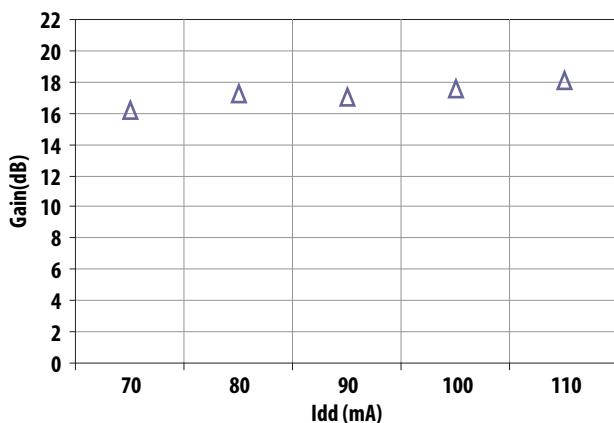


Figure 9. Gain vs I_{dd} at 4.8 V Tuned for Optimum IIP3 and F_{min} at 700 MHz

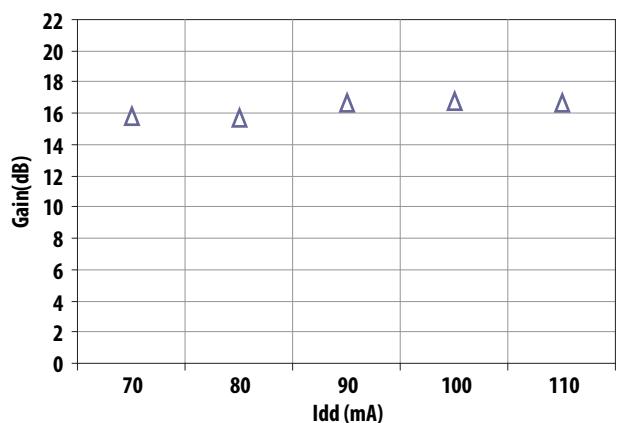


Figure 10. Gain vs I_{dd} at 4.8 V Tuned for Optimum IIP3 and F_{min} at 900 MHz

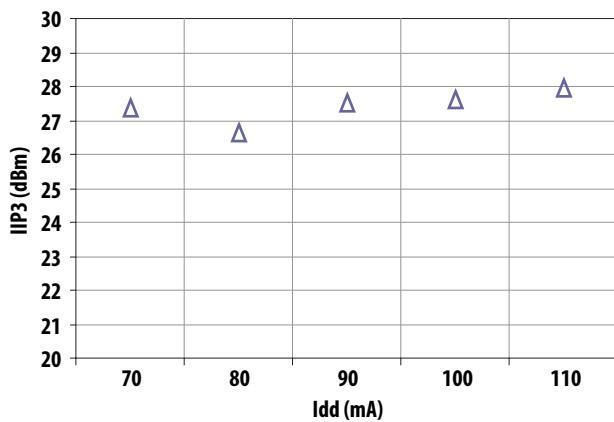


Figure 11. IIP3 vs I_{dd} at 4.8 V Tuned for Optimum IIP3 and F_{min} at 700 MHz

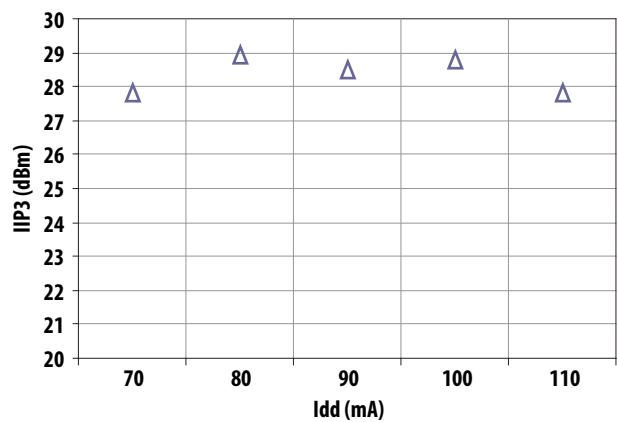


Figure 12. IIP3 vs I_{dd} at 4.8 V Tuned for Optimum IIP3 and F_{min} at 900 MHz

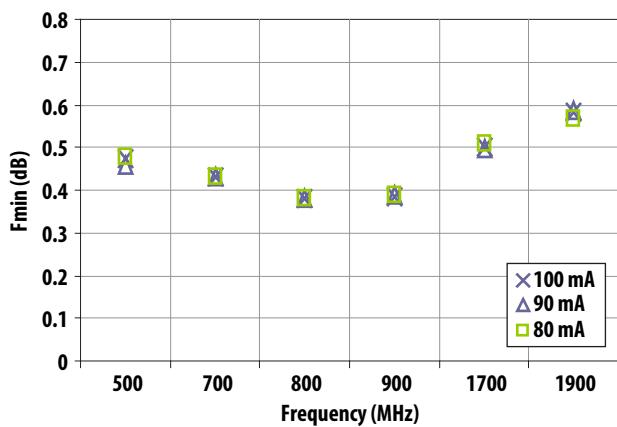


Figure 13. Fmin vs Frequency and Idd at 4.8 V

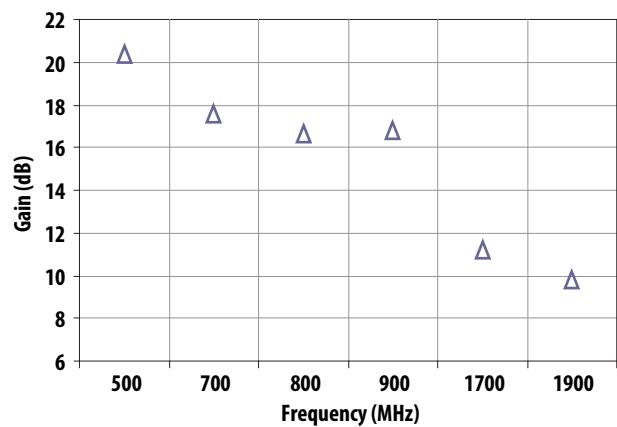


Figure 14. Gain vs Frequency for Optimum IIP3 and Fmin at 4.8 V 100 mA

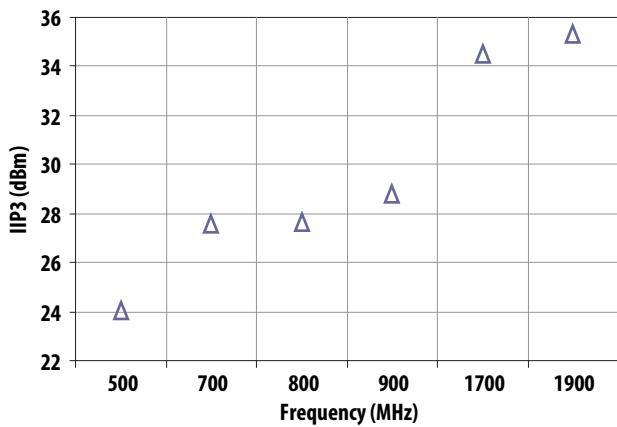


Figure 15. IIP3 vs Frequency for Optimum IIP3 and Fmin at 4.8 V 100 mA

Below is the table showing the MGA-636P8 Reflection Coefficient Parameters tuned for Maximum IIP3, Vdd = 4.8 V, Id = 100 mA.

| Frequency (GHz) | Gamma Load position | | IIP3 (dBm) |
|--------------------|---------------------|-------|---------------|
| | Magnitude | Angle | |
| 0.50 | 0.36 | -57.7 | 22.6 |
| 0.70 | 0.36 | -57.6 | 28.4 |
| 0.80 | 0.36 | -43.2 | 28.2 |
| 0.90 | 0.27 | -39.9 | 28.9 |
| 1.70 | 0.27 | -27.9 | 34.9 |
| 1.90 | 0.27 | 0.3 | 35.7 |

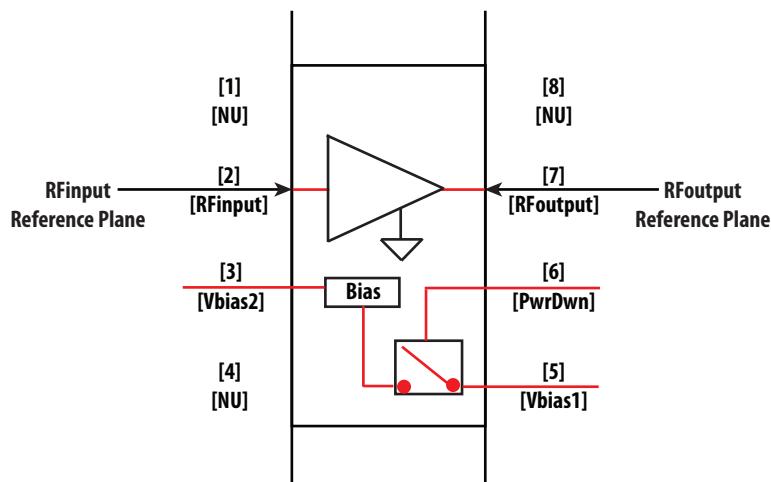


Figure 16. RFinput and RFoutput Reference Plane

Notes:

1. The Maximum IIP3 values are calculated based on Load pull measurements on approximately 100 different impedances using Focus Load pull test system.
2. Measurements are conducted on 0.010 inch thick ROGER 4350. The input reference plane is at the end of the RFin pin and the output reference plane is at the end of the RFout pin as shown in Figure 16.

Typical Performance

RF performance at $T_A = 25^\circ C$, $V_{dd} = V_{bias1} = 4.8 V$, $I_{dd} = 108 mA$, LNA mode, measured on demo board in Figure 5. Signal = CW unless stated otherwise. Application Test Circuit is shown in Figure 6 and Table 1. IIP3 test condition: $F_{RF1}-F_{RF2} = 1$ MHz with input power of -10 dBm per tone.

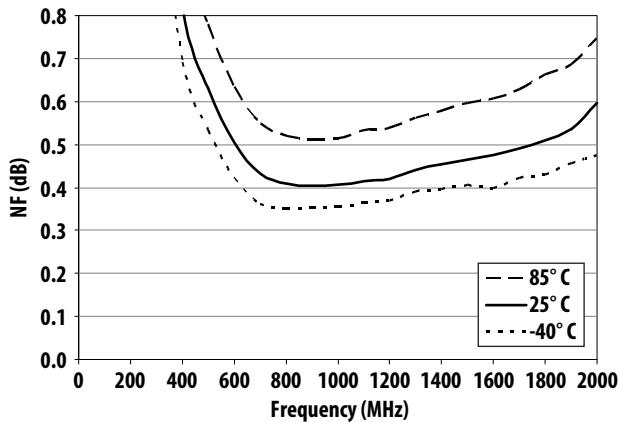


Figure 17. NF vs Frequency vs Temperature

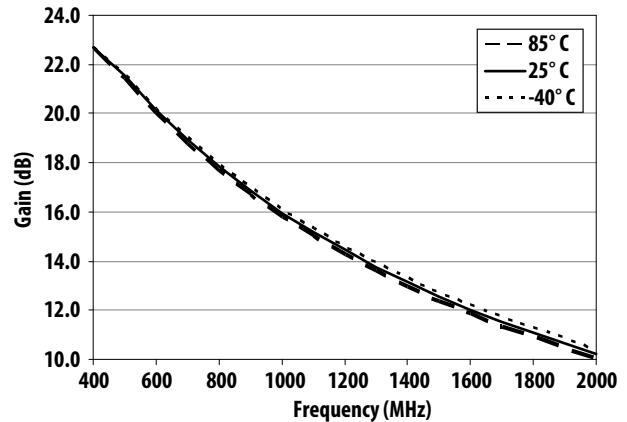


Figure 18. Gain vs Frequency vs Temperature

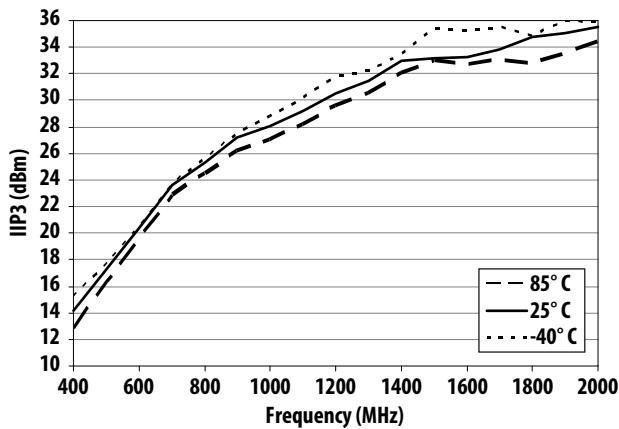


Figure 19. IIP3 vs Frequency vs Temperature

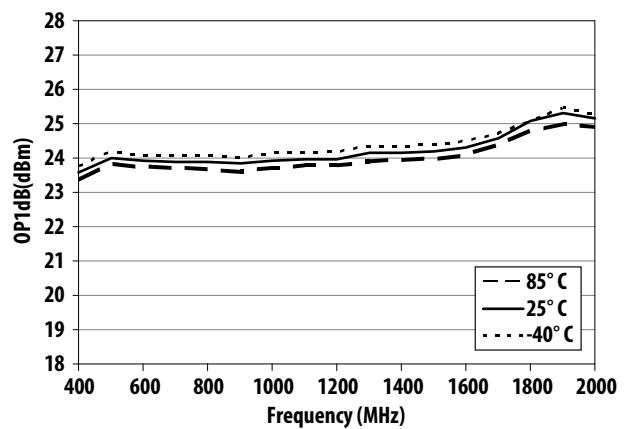


Figure 20. OP1dB vs Frequency vs Temperature

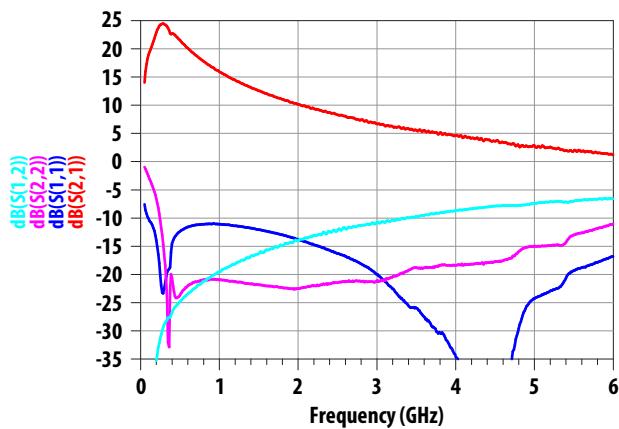


Figure 21. Input Return Loss, Output Return Loss, Gain, Reverse Isolation vs Frequency

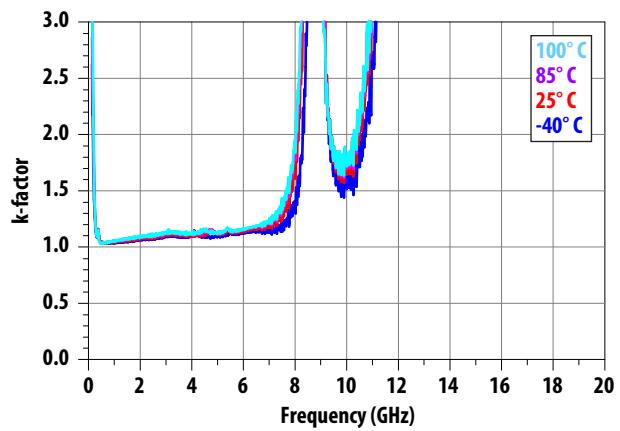


Figure 22. k-factor vs Frequency vs Temperature

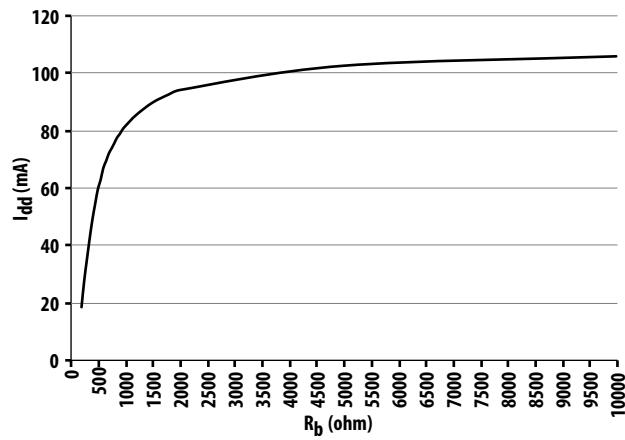


Figure 23. I_{dd} vs R_b

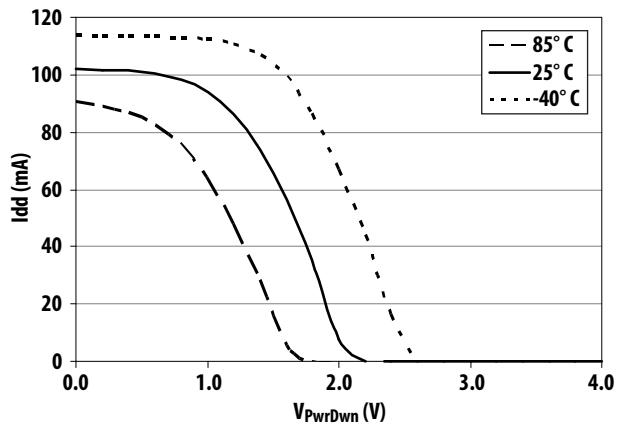


Figure 24. I_{dd} vs V_{PwrDwn}

Typical Scattering Parameters, Vdd = 4.8 V, Id = 108 mA

LNA SPAR (100 MHz – 20 GHz)

| Freq (GHz) | S11 (dB) | S11 (ang) | S21 (dB) | S21 (ang) | S12 (dB) | S12 (ang) | S22 (dB) | S22 (ang) |
|---------------|-------------|--------------|-------------|--------------|-------------|--------------|-------------|--------------|
| 0.1 | -3.611 | -62.842 | 30.561 | 136.999 | -34.551 | 62.629 | -15.454 | -100.227 |
| 0.5 | -10.75 | -141.835 | 21.562 | 98.647 | -25.1 | 65.794 | -21.768 | 173.774 |
| 0.7 | -11.393 | -159.056 | 19.067 | 89.008 | -22.486 | 65.115 | -23.274 | 176.757 |
| 0.9 | -11.693 | -171.846 | 17.088 | 81.239 | -20.477 | 63.144 | -23.435 | -175.622 |
| 1.0 | -12.003 | -176.697 | 16.247 | 77.798 | -19.607 | 61.903 | -24.023 | -169.048 |
| 1.5 | -12.658 | 161.534 | 12.916 | 62.727 | -16.314 | 54.394 | -22.335 | -157.583 |
| 1.7 | -12.53 | 154.197 | 11.855 | 57.342 | -15.332 | 51.078 | -20.648 | -161.025 |
| 1.9 | -12.404 | 147.907 | 10.906 | 52.163 | -14.463 | 47.752 | -19.362 | -164.643 |
| 2.0 | -12.379 | 145.023 | 10.472 | 49.657 | -14.065 | 46.022 | -18.873 | -166.072 |
| 2.5 | -12.524 | 132.944 | 8.569 | 37.635 | -12.364 | 37.489 | -17.143 | -171.539 |
| 3 | -13.356 | 123.107 | 7.083 | 26.504 | -10.943 | 28.854 | -15.991 | -174.201 |
| 3.5 | -14.336 | 114.678 | 5.844 | 15.468 | -9.794 | 19.876 | -15.602 | -179.46 |
| 4 | -15.464 | 103.233 | 4.756 | 5.444 | -8.846 | 11.572 | -14.891 | 177.251 |
| 4.5 | -16.075 | 89.916 | 3.908 | -5.273 | -7.978 | 2.026 | -13.836 | 161.01 |
| 5 | -15.98 | 79.553 | 3.084 | -15.148 | -7.323 | -6.929 | -12.579 | 146.587 |
| 5.5 | -15.742 | 62.755 | 2.344 | -25.098 | -6.757 | -16.231 | -11.308 | 133.363 |
| 6 | -15.688 | 50.395 | 1.686 | -34.558 | -6.287 | -25.298 | -10.288 | 121.972 |
| 7 | -17.293 | 40.867 | 0.539 | -52.328 | -5.474 | -42.892 | -9.2 | 104.475 |
| 8 | -23.851 | 68.823 | -0.256 | -69.296 | -4.831 | -60.283 | -9.074 | 95.197 |
| 9 | -19.948 | 145.615 | -1.09 | -85.871 | -4.478 | -77.706 | -9.337 | 88.367 |
| 10 | -15.337 | 144.42 | -1.671 | -102.123 | -4.108 | -95.651 | -8.526 | 78.112 |
| 11 | -14.047 | 129.044 | -2.544 | -120.208 | -4.249 | -115.535 | -7.598 | 48.997 |
| 12 | -12.433 | 104.57 | -3.529 | -135.218 | -4.696 | -132.217 | -6.371 | 28.359 |
| 13 | -9.432 | 93.835 | -4.488 | -151.951 | -5.197 | -150.835 | -4.998 | 26.293 |
| 14 | -6.416 | 81.489 | -5.847 | -162.095 | -6.312 | -163.011 | -5.407 | 16.024 |
| 15 | -5.585 | 68.225 | -5.445 | -168.582 | -5.676 | -170.476 | -8.272 | 15.731 |
| 16 | -5.651 | 57.754 | -5.184 | 172.519 | -5.19 | 168.847 | -6.291 | 6.112 |
| 17 | -4.91 | 46.32 | -6.704 | 156.563 | -6.646 | 151.286 | -4.337 | -20.813 |
| 18 | -4.432 | 34.876 | -7.895 | 144.747 | -7.778 | 138.297 | -3.486 | -31.185 |
| 19 | -3.638 | 18.869 | -8.76 | 131.758 | -8.607 | 124.14 | -2.747 | -26.804 |
| 20 | -3.147 | 2.127 | -8.894 | 121.339 | -8.745 | 112.553 | -2.767 | -18.826 |

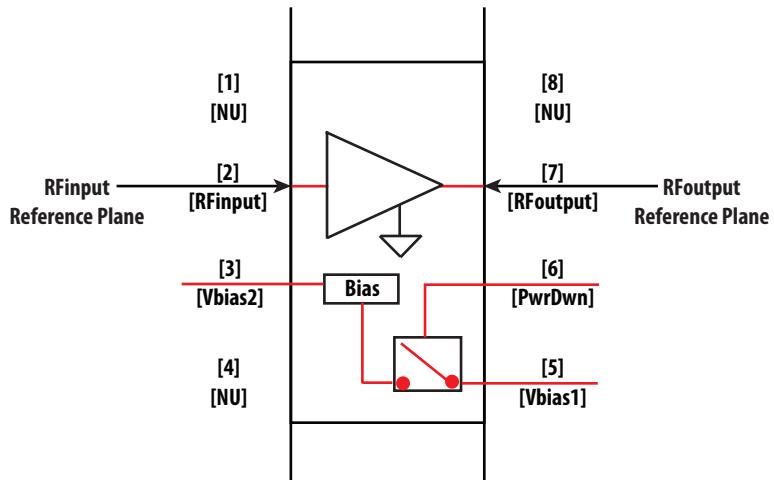


Figure 25. RFinput and RFoutput Reference Plane

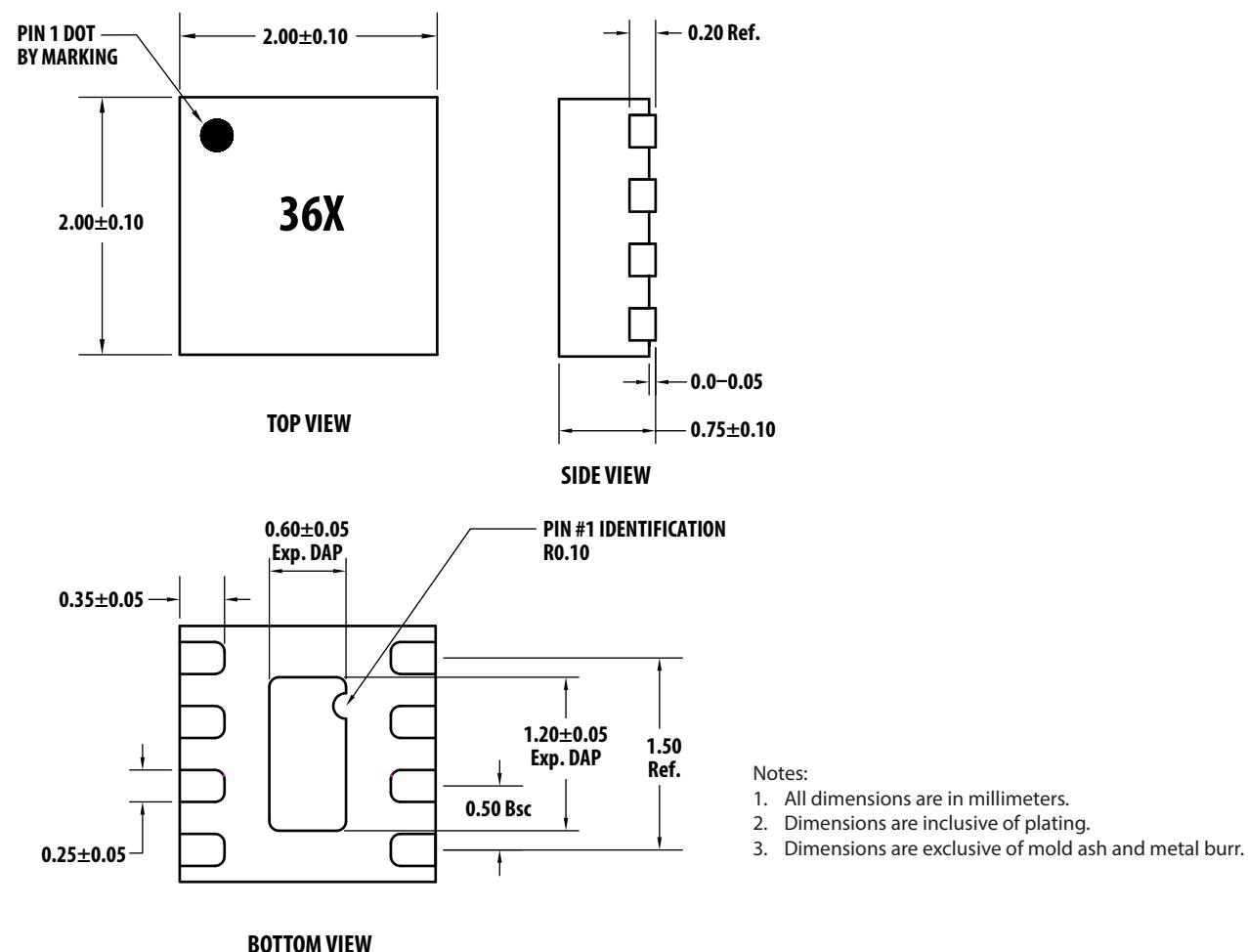
Typical Noise Parameters, Vdd = 4.8 V, Id = 108 mA

| Freq GHz | Fmin dB | Γ_{opt} Mag. | Γ_{opt} Ang. | $R_{n/50}$ |
|-------------|------------|-------------------------------|-------------------------------|------------|
| 0.5 | 0.472 | 0.078 | -31.8 | 0.038 |
| 0.7 | 0.432 | 0.080 | 11.5 | 0.037 |
| 0.8 | 0.379 | 0.081 | 33.2 | 0.037 |
| 0.9 | 0.386 | 0.082 | 54.8 | 0.038 |
| 1.7 | 0.5 | 0.092 | 228 | 0.043 |
| 1.9 | 0.582 | 0.094 | 271 | 0.043 |

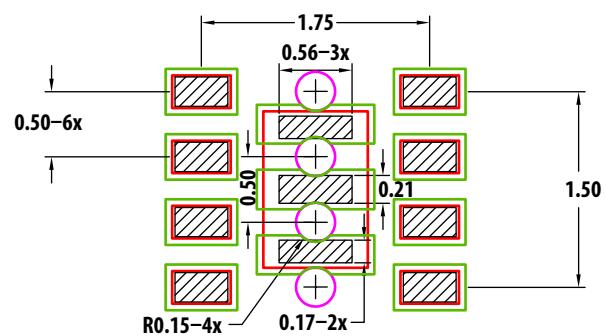
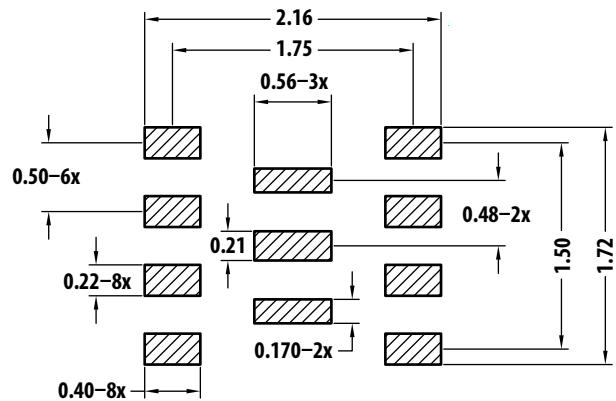
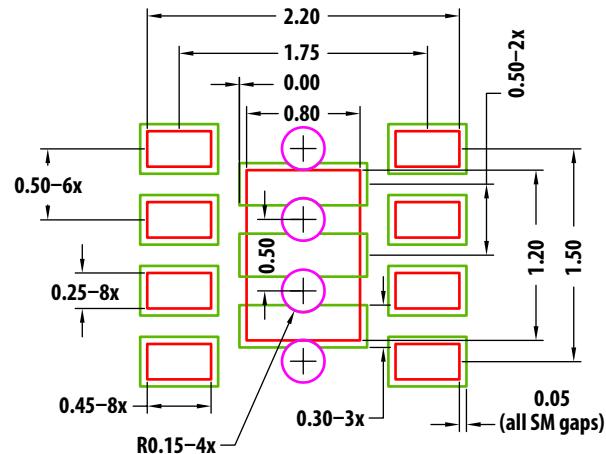
Notes:

1. The Fmin values are based on noise figure measurements at 100 different impedances using Focus source pull test system. From these measurements a true Fmin is calculated.
2. Scattering and noise parameters are measured on coplanar waveguide made on 0.010 inch thick ROGER 4350. The input reference plane is at the end of the RFinput pin and the output reference plane is at the end of the RFoutput pin as shown in Figure 25.

DFN2X2 Package Dimensions



Recommended PCB Land Pattern and Stencil Design



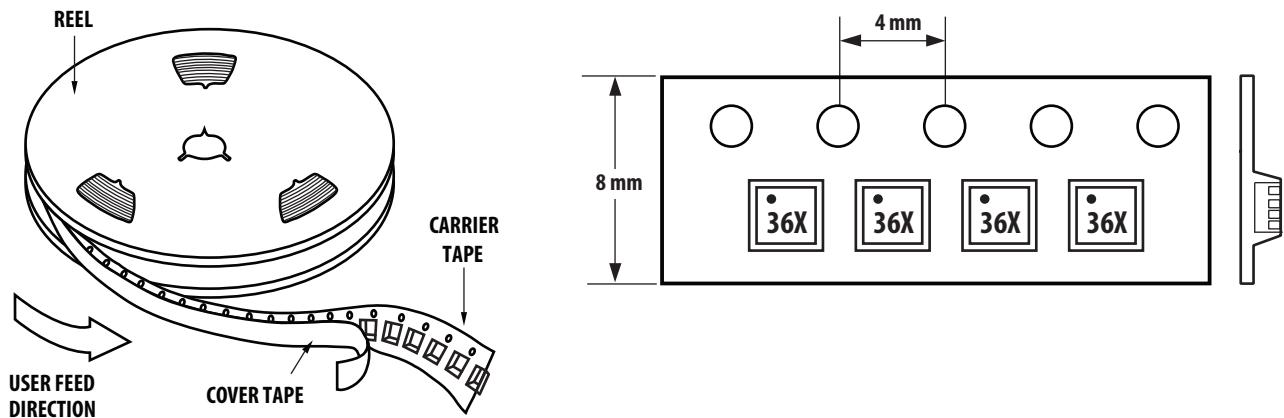
□ Metal surface
□ Soldermask Open

All Dimension are in millimeters

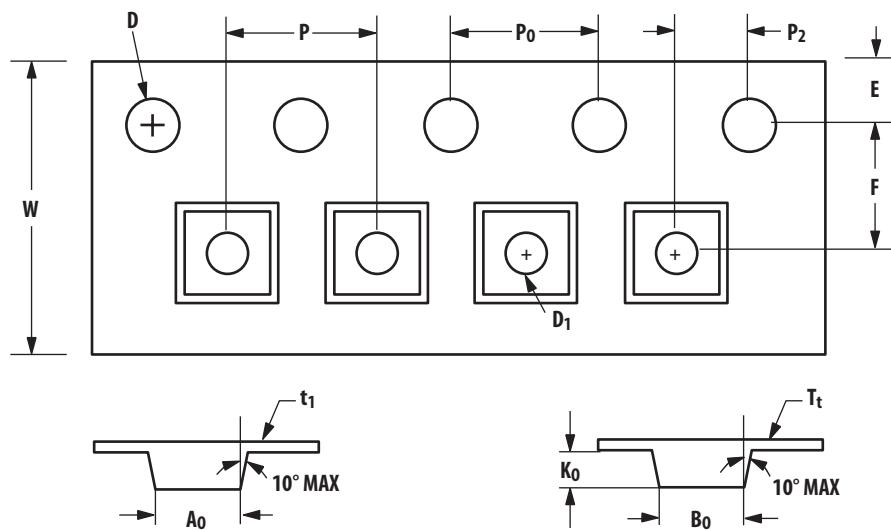
Notes:

1. Stencil thickness is 0.1 mm (4 mils).
2. All dimensions are in mm unless otherwise specified.

Device Orientation

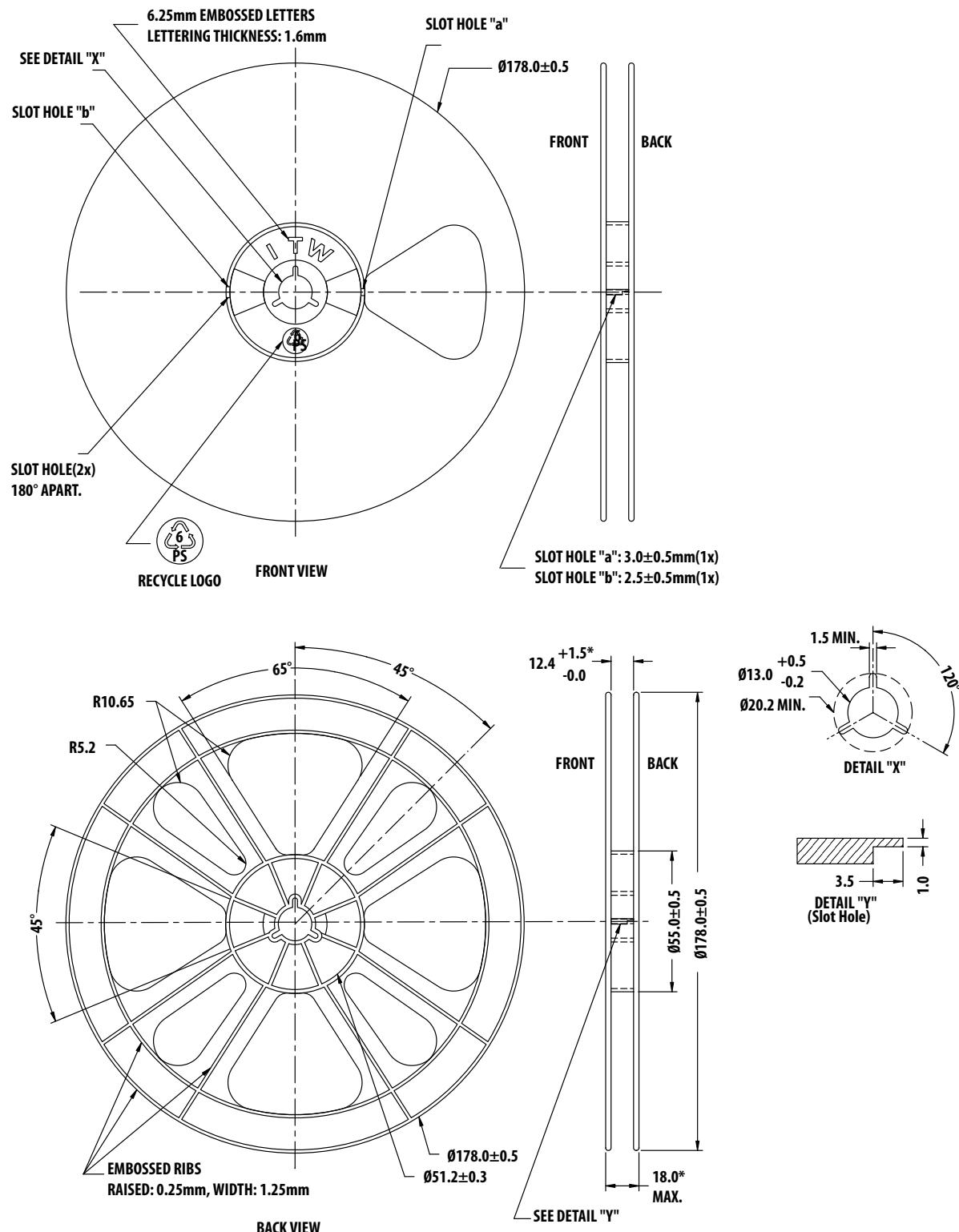


Tape Dimensions



| DESCRIPTION | | SYMBOL | SIZE (mm) | SIZE (INCHES) |
|--------------|--|----------------|---------------|-----------------|
| CAVITY | LENGTH | A ₀ | 2.30 ± 0.05 | 0.091 ± 0.004 |
| | WIDTH | B ₀ | 2.30 ± 0.05 | 0.091 ± 0.004 |
| | DEPTH | K ₀ | 1.00 ± 0.05 | 0.039 ± 0.002 |
| | PITCH | P | 4.00 ± 0.10 | 0.157 ± 0.004 |
| | BOTTOM HOLE DIAMETER | D ₁ | 1.00 ± 0.25 | 0.039 ± 0.002 |
| PERFORATION | DIAMETER | D | 1.50 ± 0.10 | 0.060 ± 0.004 |
| | PITCH | P ₀ | 4.00 ± 0.10 | 0.157 ± 0.004 |
| | POSITION | E | 1.75 ± 0.10 | 0.069 ± 0.004 |
| CARRIER TAPE | WIDTH | W | 8.00 ± 0.30 | 0.315 ± 0.012 |
| | THICKNESS | t ₁ | 0.254 ± 0.02 | 0.010 ± 0.0008 |
| COVER TAPE | WIDTH | C | 5.4 ± 0.10 | 0.205 ± 0.004 |
| | TAPE THICKNESS | T _t | 0.062 ± 0.001 | 0.0025 ± 0.0004 |
| DISTANCE | CAVITY TO PERFORATION (WIDTH DIRECTION) | F | 3.50 ± 0.05 | 0.138 ± 0.002 |
| | CAVITY TO PERFORATION (LENGTH DIRECTION) | P ₂ | 2.00 ± 0.05 | 0.079 ± 0.002 |

Reel Dimensions – 7 inch



For product information and a complete list of distributors, please go to our web site: www.avagotech.com

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